	На	Ticket Number :										
	Co	e: 4C234										
	Code: 4G234 Il B.Tech. I Semester Supplementary Examinations May 2019											
Electromagnetic Fields												
(Electrical and Electronics Engineering)												
	Mo	x. Marks: 70 Time: 3 Hours										
	Answer all five units by choosing one question from each unit (5 x 14 = 70 Marks)											
		UNIT–I										
1.	a)	State and explain vector form of Coulombs law? 4N	1									
	b)	Derive the expression for Electric Field intensity and potential at a point P which is situated h meter away from the disc along its axis. The disc is charged uniformly with a charge density of ${}_{s}$ C/m ² .	1									
		OR	•									
2.	a)	Derive the expression for energy density in an electrostatic field. 7N	1									
	b)	Point charges 1 mC and -2 mC are located at (3,2,-1) and (-1,-1,4), respectively.										
		Calculate the electric force on a 10 nC charge located at (0,3,1) and the electric field intensity at that point.	л									
			1									
3.	a)	Derive the expression for the energy stored in a parallel plate capacitor 8M	1									
	b)	Determine the capacitance of a capacitor consisting of two parallel metal plates of 30										
		cm X30 cm surface area, separated by 5 mm gap in air. What is the total energy stored										
		by the capacitor if the capacitor if the capacitor is charged with 500 V? What is the energy density? 6N	1									
		OR										
4.	a)	Define Dipole and Dipole moment? Derive the expression for potential due to dipole? 7N	1									
	b)	Explain Polarization of dielectric materials? 7N	1									
F		UNIT-III Obtain an expression for Magnetic field intensity due to an infinitely long current corrying										
5.	a)	Obtain an expression for Magnetic field intensity due to an infinitely long current carrying conductor? 7N	1									
	b)	Derive the expression for Vector Magnetic Potential. 7N										
	,	OR										
6.		A uniform solenoid 100 mm in diameter and 400 mm long has 100 turns of wire and a										
		current of I=3A.Find the magnetic field on the axis of the solenoid a) At the center b) At one end c) Half way from the center to one end. 14M	л									
		end c) Half way from the center to one end. 14M	1									
7.	a)	Derive the expression for energy stored in a magnetic field.	1									
	b)	Derive the self-inductance of a solenoid 7M	1									
		OR										
8.	a)	What is a magnetic dipole? How does it differ from an electric dipole? 7M Design the second secon										
	b)	Derive the expression for inductance of a solenoid using Amperes circuital law. 7N UNIT-V	1									
9.	a)	Distinguish clearly the dynamically induced EMF and statically induced EMF explain with										
	~)	neat diagram.	1									
	b)	Find the EMF developed around a circular path with radius r=0.5m in the plane z=0 at t=0										
		if(i) B=0.1 sin(377t)a _z (ii) B=0.1sin(377t/r)a _r .	1									
4.0												
10.		Compare and Contrast Electric and Magnetic Fields? 14N ***	1									

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Max	. Mc	arks: 70	([]	ecii	icui	unu	LIEC	101	IICS I	Ingi		ng)		Time: 3 Ho	Urs
Answer all five units by choosing one question from each unit (5 x 14 = 70 Marks)															
UNIT-I															
1.	a)	Convert the	follo	wing	num	bers	into	decir	mal:	_					
		i. 1001				1(B0	CD)								
		ii. (1100 iii. (CF.5		1.11	I)2										
		iv. (234)													10M
	b)	Explain with correcting end		•					•	de i	s us	seful	for d	etecting and	4M
								OF	R						
2.	a)	complem	ient n	nethe	od. F	ind t	he re	sult i	in sig	in-ma	agnit	ude.	•	ent and 2's	
		ii.) What is t number s			calleo	d in c	case	of D	ecim	al, bi	nary	, octa	al and	hexadecimal	7M
	b)	Find the Ex numbers:				and	its 9)'s c	ompl	emei	nt fo	r the	e follov	wing decimal	7M
							l	JNIT	-11]					
3.	a)				-			-		-		•	nent it	using basic	
		gates only.	f(A,	B,C,	<i>D</i>) =	\sum_{m}	(2,3,	5,13,	14)+	d(8,	9,10,	11)			7M
	b)	Simplify the		•				tion	to PC	DS fo	rm.				
		f(w, x, y, z)	$=\sum_{i=1}^{n}$	(0,1,	2,5,8	8,10,	13)								7M
								OF	ł						
4.	a)	Minimize th prime implic	•		•			•		•				the essential	
		Y(A, B, C, D)	$) = \sum$	$\int_{m}(4,$	5,7,1	12,14	,15)-	$+\sum a$	d(3,8	,10)					7M
	b)	Use the tabu	ular p	roce	dure	to si	mpli	y the	e give	en ex	pres	sion			
		f(v, w, x, y, z)	$z) = \sum_{i=1}^{n}$	$\sum_{m} (C$), 4, 12	2,16,	19,24	, 27,	28,29	9,31)					7M
5.	a)	Implement t	he fo	llowi	na fu	nctio		JNIT- ing a] MU	х				
		F(A, B, C) =			-										7M
	b)	Realize two					usin	a 4X	2 PR	OM					7 101
	~)	$F_1(A_1, A_0) =$			i an	~ 1 2		3 17							
		$F_1(A_1, A_0) =$	— <i>m</i>		5.7)										
		-211,10/-	Δm^{\prime}	,.,	-, • /										7M

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OR

6.	a)	Implement the following logic function using an 8X1 MUX	
		$F(AB, C, D) = \sum_{m} (1, 3, 4, 11, 12, 13, 14, 15).$	7M
	b)	Compare the three combinational PLDs.	7M
		UNIT–IV	
7.	a)	What are the applications of flip-flops?	2M
	b)	Design a mod-7 synchronous counter using S-R flip-flops.	12M
		OR	
8.	a)	What is twisted ring counter? Write the advantages and disadvantages of ring counter compared to ripple counter	4M
	b)	Design 3-bit counter which counts in the following sequence	
		$0 \rightarrow 2 \rightarrow 5 \rightarrow 3 \rightarrow 4 \rightarrow 0 \rightarrow 2 \rightarrow \dots etc$	10M
		UNIT-V	
9.	a)	What are the capabilities and limitations of finite state machines?	2M
	b)	Find the equivalence partition and corresponding reduced machine in	

b) Find the equivalence partition and corresponding reduced machine in standard form for the machine given below.

PS	NS,Z								
P3	X=0	X=1							
Α	E,0	D,1							
В	F,0	D,0							
С	E,0	B,1							
D	F,0	B,0							
E	C ,0	F,1							
F	B,0	C ,0							
OR									

12M

2M

- 10. a) Define the "State equivalence and machine equivalence" with reference to sequential machines.
 - b) What are the conditions for two machines to be equivalent? for the machine given in table, find the equivalence partition and corresponding reduced machine in standard form.

PS	NS,Z								
	X=0	X=1							
Α	F,0	B,1							
В	G,0	A,1							
С	B,0	C,1							
D	C ,0	B,1							
E	D,0	A,1							
F	E,1	F,1							
G	E,1	G,1							

12M

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Code: 4G233 II B.Tech. I Semester Supplementary Examinations May 2019 Electrical Circuits – I (Electrical and Electronics Engineering) Max. Marks: 70 Answer all five units by choosing one question from each unit (5 x 14 = 70 Marks) ********															
1. a)	Discuss the con	cept	of sc	ource	trans		I T-I natio	n tec	hniqu	Je.					7M
b)											d Z ii	n Fig.′	1.		7M
b) Find the equivalent resistance between the terminals Y and Z in Fig.1. $ \begin{array}{c} $															
							Fig.1								
							OR								
2. a)	Explain the follow i. Twig ii. Link iii. Oriented gr iv. Incident ma	aph	term	s with	n refe	erenc	ce to	netw	ork t	opolo	ogy v	vith ar	n exa	ample.	8M
b)	Write the proper	ties o	of tie	-set i	natrix	x and	d cut	-set r	natri	x					6M
							UNI								
3. a)	Show that reson and upper half-free			-		of R	LC s	eries	circ	uit is	geo	metrio	c me	ean of lower	7M
b)	With respect to s to the Q-factor at				t circ	uit, p	orove	e that	: ban	dwid	th is	invers	sely	proportional	7M
							OR								
4. a)	Define the follow i) Amplitude ii) Instantane iii) Frequency iv) Phase	e of a					-	quan	itity						8M
b)	Discuss about Po	ower	trian	gle a	-	owei UNI		or in	ac ci	ircuit	S.				6M
5. a)	State and prove	the s	uper	posit	ion th	neore	em w	vith th	ie he	lp of	an e	xamp	le.		7M
b)	Find R _{AB} in Fig.2,	, for r	naxii 16v	mum	64				a 	llcula	te m	aximu	ım p	ower.	

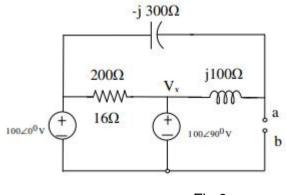
в

7M

OR

6. Find the Thevenin equivalent circuit for the circuit shown below Fig.3.

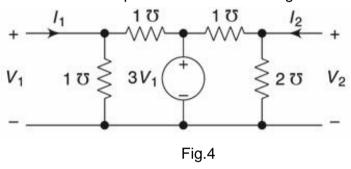
14M





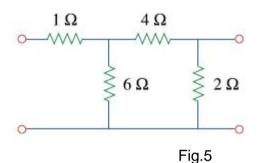
UNIT-IV

7. Find the Y-parameters for the two port network shown in fig.4





8. a) Obtain the *z* -parameters for the network in Fig.5



b) Determine the h-parameters with the following data:

(i) With the output terminals short circuited, $V_1=25V$, $I_1=1A$, $I_2=2A$

(ii) With the input terminals open circuited, V_1 =10V, V_2 =50V, I_2 =2A

UNIT–V

- 9. a) Derive the relation between self inductance, mutual inductance and coefficient of 7M coupling.
 - b) A magnetic circuit consists of an iron ring of mean circumference 80 cm with crosssectional area of 12 cm2 throughout. A current of 2A in the magnetising coil of 200 turns produce a total flux of 1.2 mwb in the iron. Calculate: i) the flux density in the iron ii) the absolute and relative permeability of iron. iii) the reluctance of the circuit.

OR

- 10. a) Explain the importance of dot convention in coupled circuits.6M
 - b) Define: (i) Flux (ii) m.m.f (iii) Reluctance (iv) Magnetic field intensity. 8M

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8M

14M

6M